MBRF835CT – MBRF8150CT



8A, 35V - 150V Schottky Barrier Rectifier

FEATURES

TAIWAN

• AEC-Q101 qualified available

EMICONDUCTOR

- Low power loss, high efficiency
- Guard ring for overvoltage protection
- High surge current capability
- UL Recognized File # E-326243
- RoHS Compliant
- Halogen-free according to IEC 61249-2-21

APPLICATIONS

- Switching mode power supply (SMPS)
- Adapters
- DC to DC converters

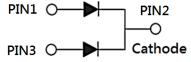
MECHANICAL DATA

- Case: ITO-220AB
- Molding compound meets UL 94V-0 flammability rating
- Terminal: Matte tin plated leads, solderable per J-STD-002
- Mounting torque: 0.56 N⋅m maximum
- Meet JESD 201 class 2 whisker test
- Polarity: As marked
- Weight: 1.70g (approximately)

KEY PARAMETERS			
PARAMETER	VALUE	UNIT	
I _F	8	А	
V _{RRM}	35 - 150	V	
I _{FSM}	150	А	
T _{J MAX}	150	°C	
Package	ITO-220AB		
Configuration	Dual dies		







ABSOLUTE MAXIMUM RATINGS (T _A = 25°C unless otherwise noted)									
		MBRF	MBRF	MBRF	MBRF	MBRF	MBRF	MBRF	
PARAMETER	SYMBOL	835	845	850	860	890	8100	8150	UNIT
		СТ	СТ	СТ	СТ	СТ	СТ	СТ	
		MBRF	MBRF	MBRF	MBRF	MBRF	MBRF	MBRF	
Marking code on the device		835	845	850	860	890	8100	8150	
		СТ	СТ	СТ	СТ	СТ	СТ	СТ	
Repetitive peak reverse voltage	V _{RRM}	35	45	50	60	90	100	150	V
Reverse voltage, total rms value	V _{R(RMS)}	24	31	35	42	63	70	105	V
Forward current	I _F				8				Α
Surge peak forward current, 8.3ms single half sine wave superimposed on rated load	I _{FSM}	I _{FSM} 150			A				
Critical rate of rise of off-state voltage	dv/dt 10,000			V/µs					
Junction temperature	TJ	T _J -55 to +150		°C					
Storage temperature	T _{STG}			-{	55 to +15	50			°C



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THERMAL PERFORMANCE			
PARAMETER	SYMBOL	ТҮР	UNIT
Junction-to-case thermal resistance	R _{eJC}	6	°C/W

ELECTRICAL SPECIFICATIONS (T _A = 25°C unless otherwise noted)						
PARAMETER		CONDITIONS	SYMBOL	ΤΥΡ	MAX	UNIT
	MBRF835CT	I _F = 4A,T _J = 25°C		_	0.55	V
	MBRF845CT			_	0.00	v
	MBRF850CT			_	0.70	v
Forward voltage per diode ⁽¹⁾	MBRF860CT		VF		0.70	v
	MBRF890CT			-	0.85	V
	MBRF8100CT					
	MBRF8150CT			-	0.95	V
	MBRF835CT	T _J = 25°C				
	MBRF845CT		I _R			
	MBRF850CT					
	MBRF860CT			-	100	μA
	MBRF890CT					
	MBRF8100CT					
Reverse current @ rated V_R per	MBRF8150CT					
diode ⁽²⁾	MBRF835CT			-	15	mA
	MBRF845CT	T _J = 125°C			10	
	MBRF850CT			_	10	mA
	MBRF860CT				10	
	MBRF890CT					
	MBRF8100CT			-	5	mA
	MBRF8150CT					

Notes:

1. Pulse test with PW = 0.3ms

2. Pulse test with PW = 30ms

ORDERING INFORMATION			
ORDERING CODE ⁽¹⁾⁽²⁾	PACKAGE	PACKING	
MBRF8xCT	ITO-220AB	50 / Tube	
MBRF8xCTH	ITO-220AB	50 / Tube	

Notes:

- 1. "x" defines voltage from 35V(MBRF835CT) to 150V(MBRF8150CT)
- 2. "H" means AEC-Q101 qualified



10

1

0.1

0.01

INSTANTANEOUS REVERSE CURRENT (mA)

Fig.2 Typical Junction Capacitance

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CHARACTERISTICS CURVES

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$

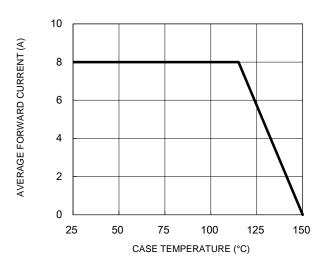


Fig.1 Forward Current Derating Curve

Fig.3 Typical Reverse Characteristics

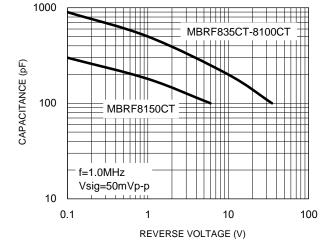
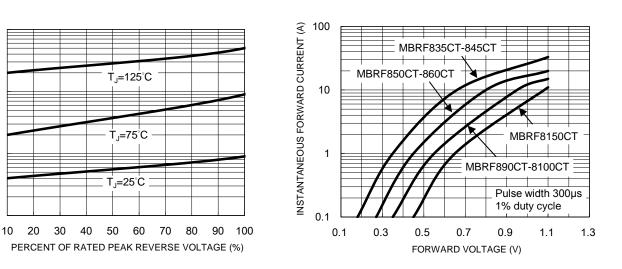


Fig.4 Typical Forward Characteristics



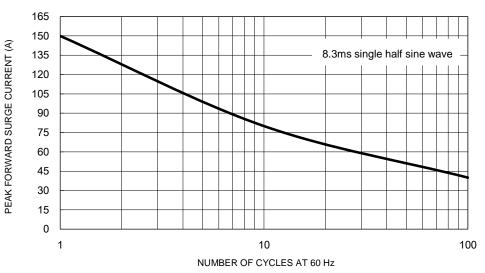


Fig.5 Maximum Non-Repetitive Forward Surge Current

Version: J2105



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CHARACTERISTICS CURVES

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$

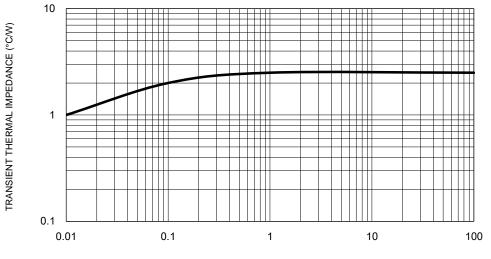


Fig.6 Typical Transient Thermal Impedance

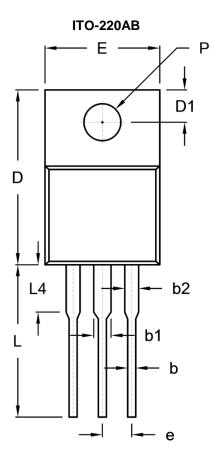
PULSE DURATION (s)

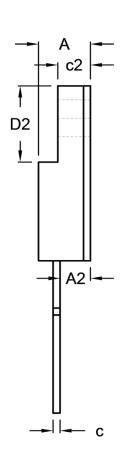


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PACKAGE OUTLINE DIMENSIONS





DIM.	Unit (mm)		Unit ((inch)	
	Min.	Max.	Min.	Max.	
A	4.30	4.70	0.169	0.185	
A2	2.30	2.96	0.091	0.117	
b	0.50	0.90	0.020	0.035	
b1	-	1.80	-	0.071	
b2	0.95	1.45	0.037	0.057	
с	0.46	0.76	0.018	0.030	
c2	2.50	3.16	0.098	0.124	
D	14.80	15.50	0.583	0.610	
D1	2.40	3.20	0.094	0.126	
D2	6.30	6.90	0.248	0.272	
E	9.60	10.30	0.378	0.406	
е	2.41	2.67	0.095	0.105	
L	12.60	13.80	0.496	0.543	
L4	-	4.10	-	0.161	
Р	3.00	3.40	0.118	0.134	

MARKING DIAGRAM

雪別 GYWW <mark>F</mark>
P/N
→ + • • •

P/N	= Marking Code
G	= Green Compound
YWW	= Date Code
F	= Factory Code



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